

DEVICE NUMBER :	DIR-038-014	REV: _	1.2
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5mm Infrared LED ,T-1 3/4

Features:

- · High radiant intensity
- Peak wavelength λ p=940nm
- View angle 20°
- High reliability
- · 2.54mm Lead spacing

Description:

- EVERLIGHT's Infrared Emitting Diode (IR383) is a high intensity diode, molded in a blue transparent plastic package.
- The device is spectrally matched with phototransistor, photodiode and infrared receiver module.

Applications :

- · Free air transmission system
- Optoelectronic switch
- · Floppy disk drive
- Infrared applied system
- Smoke detector

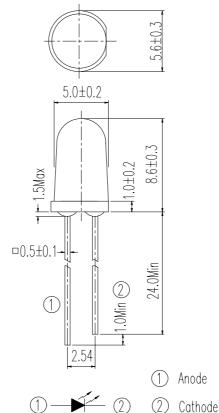
PART NO.	CHIP	LENS COLOR	
TARTINO.	MATERIAL		
IR	GaAlAs	Blue	



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Package Dimensions :



Notes:

- 1.All dimensions are in millimeter.
- 2. Protruded resin under flange 1.5 mm Max.
- 3.Lead spacing is measured where the lead emerge from the package.
- 4.Lens color : Blue transparent.
- 5. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 6.These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
- 7.When using this product, please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



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■ Absolute Maximum Ratings at Ta = 25 $^{\circ}$ C

Parameter	Symbol	Rating	Unit	Notice
Continuous Forward Current	I _F	50	mA	
Peak Forward Current Pulse width=100 μ s, Duty cycle=1%	I _{FP}	1.0	А	
Reverse Voltage	V_R	5	V	
Operating Temperature	Topr	-40 ~ +85	$^{\circ}\!\mathbb{C}$	
Storage Temperature	Tstg	-40 ~ +85	$^{\circ}\!\mathbb{C}$	
Soldering Temperature	Tsol	260	$^{\circ}\! \mathbb{C}$	4mm from mold body less than 5 seconds
Power Dissipation at(or below) 25°C Free Air Temperature	Pd	100	mW	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
		7.8	20			I _F =20mA
Radiant Intensity	Ee		90		mW/sr	I_F =100mA,tp=100 μ s, t_P /T=0.01
			900			I _F =1A,tp=100 μ s, t _P /T=0.01
Peak Wavelength	λ _P		940		nm	I _F =20mA
Spectral Bandwidth	Δλ		45		nm	I _F =20mA
			1.2	1.5		I _F =20mA
Forward Voltage	V _F		1.4	1.85	V	I_F =100mA,tp=100 μ s, t_P /T=0.01
			2.6	4.0		I _F =1A,tp=100 μ s, t _P /T=0.01
Reverse Current	I _R			10	μ A	V _R =5V
View Angle	2 ⊖ 1/2		20		deg	I _F =20mA



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MODEL NO: **IR383**

Typical Electrical/Optical/Characteristics Curves

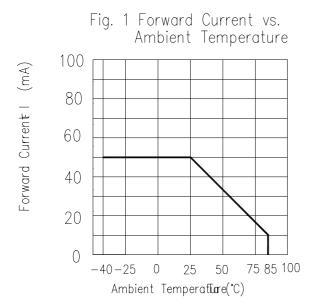
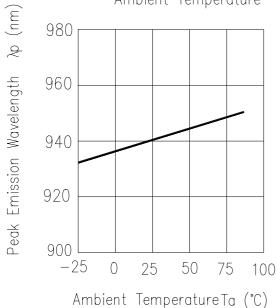
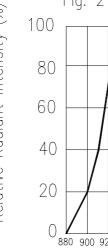


Fig. 3 Peak Emission Wavelength vs. Ambient Temperature





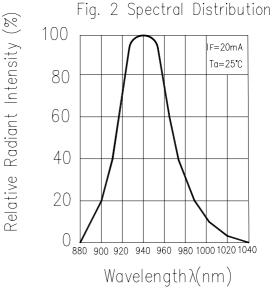
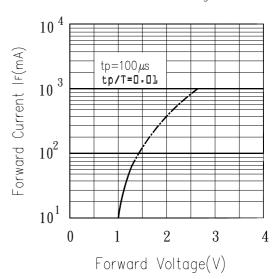


Fig. 4 Forward Current vs. Forward Voltage





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■ Typical Electrical/Optical/Characteristics Curves

Fig. 5 Relative Intensity vs. Forward Current

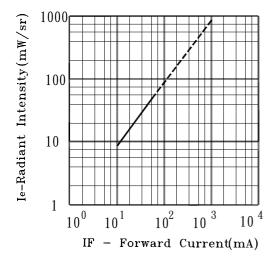


Fig. 6 Relative Radiant Intensity vs.

Angular Displacement

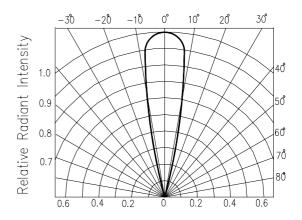


Fig. 7 Relative Intensity vs.

Ambient Temperature (℃)

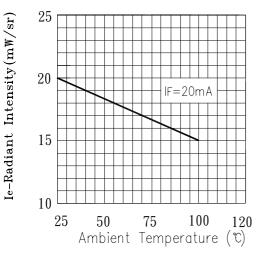
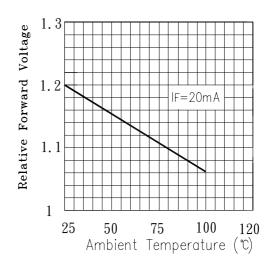


Fig. 8 Forward Current vs.

Ambient Temperature (°C)





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■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below. Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Size	Failure Judgement Criteria	Ac/Re
1	Solder Heat	TEMP: 260°C ±5 °C	5 secs	22 pcs		0/1
2	Temperature Cycle	H: +85°C 30 mins 5 mins L: -55°C 30 mins	50 cycles	22 pcs	I _R ≧Ux 2 Ee≦Lx 0.8 V _F ≧Ux 1.2	0/1
3	Thermal Shock	H: +100°C 5 mins 10 secs L: -10°C 5 mins	50 cycles	22 pcs	U :Upper specification limit L :Lower specification limit	0/1
4	High Temperature Storage	TEMP. : +100°C	1000 hrs	22 pcs		0/1
5	Low Temperature Storage	TEMP. : -55°℃	1000 hrs	22 pcs		0/1
6	DC Operating Life	I _F =20mA	1000 hrs	22 pcs		0/1
7	High Temperature / High Humidity	85℃ / 85% R.H.	1000 hrs	22 pcs		0/1



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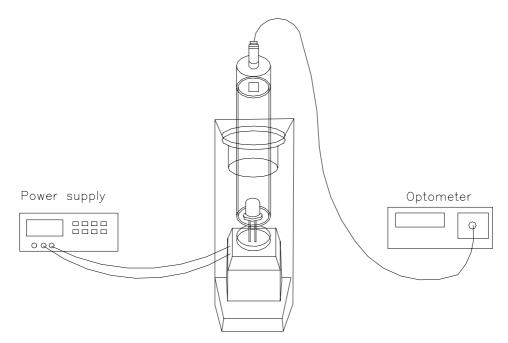
MODEL NO: IR383

Test Method For Power:

Condition : I_F =20 mA

Test Item: Radiant Intensity

Unit: mW/sr



To Distinguish Intensity:

Condition:I_F=20mA Unit: mW/sr

Bin Number	M	N	Р	Q
Min	7.8	11.0	15.0	21.0
Max	12.5	17.6	24.0	34.0

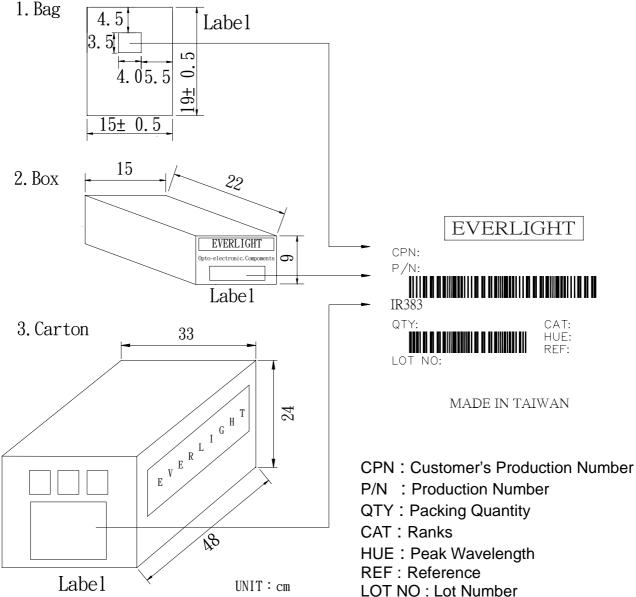


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Packing Specifications



Packing Quantity Specification

- 1. 500 Pcs/1Bag, 6 Bags/1Box
- 2. 10 Boxes/1Carton

MADE IN TAIWAN: Production place